# 2SC3470

# Silicon NPN Epitaxial

# **HITACHI**

ADE-208-1086 (Z) 1st. Edition Mar. 2001

### Application

Low frequency amplifier

#### Outline

**SPAK** 



- 1. Emitter
- 2. Collector
- 3. Base



### 2SC3470

#### **Absolute Maximum Ratings** ( $Ta = 25^{\circ}C$ )

| Item                         | Symbol           | Ratings     | Unit |
|------------------------------|------------------|-------------|------|
| Collector to base voltage    | $V_{\text{CBO}}$ | 55          | V    |
| Collector to emitter voltage | V <sub>CEO</sub> | 50          | V    |
| Emitter to base voltage      | $V_{EBO}$        | 5           | V    |
| Collector current            | I <sub>c</sub>   | 100         | mA   |
| Collector power dissipation  | P <sub>c</sub>   | 300         | mW   |
| Junction temperature         | Tj               | 150         | °C   |
| Storage temperature          | Tstg             | -55 to +150 | °C   |

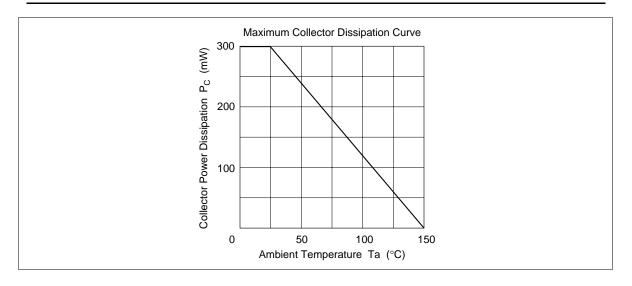
## Electrical Characteristics ( $Ta = 25^{\circ}C$ )

| Item                                    | Symbol               | Min | Тур | Max  | Unit | Test conditions                                       |
|-----------------------------------------|----------------------|-----|-----|------|------|-------------------------------------------------------|
| Collector to base breakdown voltage     | $V_{\text{(BR)CBO}}$ | 55  | _   | _    | V    | $I_{c} = 10 \ \mu A, \ I_{E} = 0$                     |
| Collector to emitter breakdown voltage  | $V_{\text{(BR)CEO}}$ | 50  | _   | _    | V    | $I_{C} = 1 \text{ mA}, R_{BE} = \infty$               |
| Emitter to base breakdown voltage       | $V_{\text{(BR)EBO}}$ | 5   | _   | _    | V    | $I_{E} = 10 \ \mu A, \ I_{C} = 0$                     |
| Collector cutoff current                | I <sub>CBO</sub>     | _   | _   | 0.5  | μΑ   | $V_{CB} = 18 \text{ V}, I_{E} = 0$                    |
| Emitter cutoff current                  | I <sub>EBO</sub>     | _   | _   | 0.5  | μΑ   | $V_{EB} = 2 \text{ V}, I_{C} = 0$                     |
| DC current transfer ratio               | h <sub>FE</sub> *1   | 250 | _   | 1200 |      | $V_{CE} = 12 \text{ V}, I_{C} = 2 \text{ mA}$         |
| Base to emitter voltage                 | $V_{\text{BE}}$      | _   | _   | 0.75 | V    | $V_{CE} = 12 \text{ V}, I_{C} = 2 \text{ mA}$         |
| Collector to emitter saturation voltage | $V_{\text{CE(sat)}}$ | _   | _   | 0.2  | V    | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$             |
| Gain bandwidth product                  | f⊤                   | _   | 230 | _    | MHz  | $V_{CE} = 12 \text{ V}, I_{C} = 2 \text{ mA}$         |
| Collector output capacitance            | Cob                  | _   | 1.8 | 3.5  | pF   | $V_{CB} = 10 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$ |

Note: 1. The 2SC3470 is grouped by  $h_{\rm FE}$  as follows.

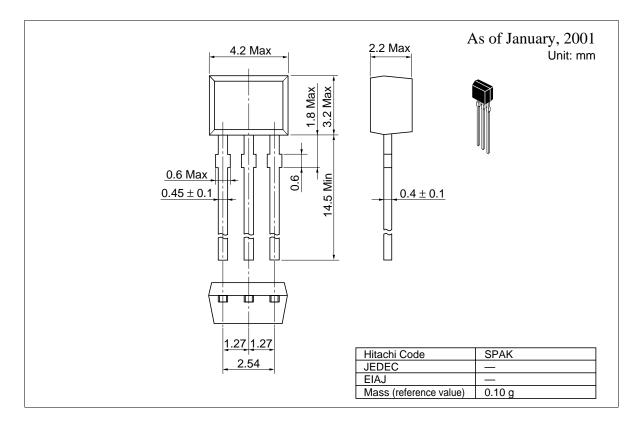
| D          | E          | F           |
|------------|------------|-------------|
| 250 to 500 | 400 to 800 | 600 to 1200 |

See characteristic curves of 2SC1345.



## 2SC3470

#### **Package Dimensions**



#### **Cautions**

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